

Researchers bring optical communication onto silicon chips

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The huge increase in computing performance in recent decades has been achieved by squeezing ever more transistors into a tighter space on microchips.

However, this downsizing has also meant packing the wiring within microprocessors ever more tightly together, leading to effects such as signal leakage between components, which can slow down communication between different parts of the chip. This delay, known as the "interconnect bottleneck," is becoming an increasing problem in high-speed computing systems.

One way to tackle the interconnect bottleneck is to use [light](#) rather than wires to communicate between different parts of a microchip. This is no easy task, however, as silicon, the material used to build chips, does not emit light easily, according to Pablo Jarillo-Herrero, an associate professor of physics at MIT.

Now, in a paper published today in the journal *Nature Nanotechnology*, researchers describe a light emitter and detector that can be integrated into silicon CMOS chips. The paper's first author is

MIT postdoc Ya-Qing Bie, who is joined by Jarillo-Herrero and an interdisciplinary team including Dirk Englund, an associate professor of electrical engineering and computer science at MIT.

The device is built from a semiconductor material called molybdenum ditelluride. This ultrathin semiconductor belongs to an emerging group of materials known as two-dimensional transition-metal dichalcogenides.

Unlike conventional semiconductors, the material can be stacked on top of silicon wafers, Jarillo-Herrero says.

"Researchers have been trying to find materials that are compatible with silicon, in order to bring optoelectronics and optical communication on-chip, but so far this has proven very difficult," Jarillo-Herrero says. "For example, gallium arsenide is very good for optics, but it cannot be grown on silicon very easily because the two semiconductors are incompatible."

In contrast, the 2-D molybdenum ditelluride can be mechanically attached to any material, Jarillo-Herrero says.

Another difficulty with integrating other semiconductors with silicon is that the materials typically emit light in the visible range, but light at these wavelengths is simply absorbed by silicon.

Molybdenum ditelluride emits light in the infrared range, which is not absorbed by silicon, meaning it can be used for on-chip communication.

To use the material as a light emitter, the researchers first had to convert it into a P-N junction diode, a device in which one side, the P side, is positively charged, while the other, N side, is negatively charged.

In conventional semiconductors, this is typically

done by introducing chemical impurities into the material. With the new class of 2-D materials, however, it can be done by simply applying a voltage across metallic gate electrodes placed side-by-side on top of the material.

"That is a significant breakthrough, because it means we do not need to introduce chemical impurities into the material [to create the diode]. We can do it electrically," Jarillo-Herrero says.

Once the diode is produced, the researchers run a current through the device, causing it to emit light.

"So by using diodes made of molybdenum ditelluride, we are able to fabricate light-emitting diodes (LEDs) compatible with silicon chips," Jarillo-Herrero says.

The device can also be switched to operate as a photodetector, by reversing the polarity of the voltage applied to the device. This causes it to stop conducting electricity until a light shines on it, when the current restarts.

In this way, the devices are able to both transmit and receive optical signals.

The device is a proof of concept, and a great deal of work still needs to be done before the technology can be developed into a commercial product, Jarillo-Herrero says.

The researchers are now investigating other materials that could be used for on-chip optical communication.

Most telecommunication systems, for example, operate using light with a wavelength of 1.3 or 1.5 micrometers, Jarillo-Herrero says.

However, molybdenum ditelluride emits light at 1.1 micrometers. This makes it suitable for use in the [silicon chips](#) found in computers, but unsuitable for telecommunications systems.

"It would be highly desirable if we could develop a similar material, which could emit and detect light at 1.3 or 1.5 micrometers in wavelength, where telecommunication through optical fiber operates,"

he says.

To this end, the researchers are exploring another ultrathin material called black phosphorus, which can be tuned to emit light at different wavelengths by altering the number of layers used. They hope to develop devices with the necessary number of layers to allow them to emit light at the two wavelengths while remaining compatible with [silicon](#).

"The hope is that if we are able to communicate on-chip via optical signals instead of electronic signals, we will be able to do so more quickly, and while consuming less power," Jarillo-Herrero says.

Provided by Massachusetts Institute of Technology

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